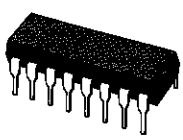
SGS-THOMSON MICROELECTRONICS

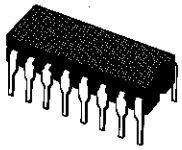
M54HC390
M74HC390

DUAL DECADE COUNTER

- HIGH SPEED
  f_{MAX} = 84 MHz (TYP.) AT V_{CC} = 5 V
- LOW POWER DISSIPATION
  I_{CC} = 4 µA (MAX.) AT T_A = 25 °C
- HIGH NOISE IMMUNITY
  $V_{NIH} = V_{NIL}$ = 28 % V_{CC} (MIN.)
- OUTPUT DRIVE CAPABILITY
  10 LSTTL LOADS
- SYMMETRICAL OUTPUT IMPEDANCE
  $|I_{OH}| = I_{OL}$ = 4 mA (MIN.)
- BALANCED PROPAGATION DELAYS
  $t_{PLH} = t_{PHL}$
- WIDE OPERATING VOLTAGE RANGE
  V_{CC} (OPR) = 2 V TO 6 V
- PIN AND FUNCTION COMPATIBLE WITH 54/74LS390



B1R
(Plastic Package)



F1R
(Ceramic Package)

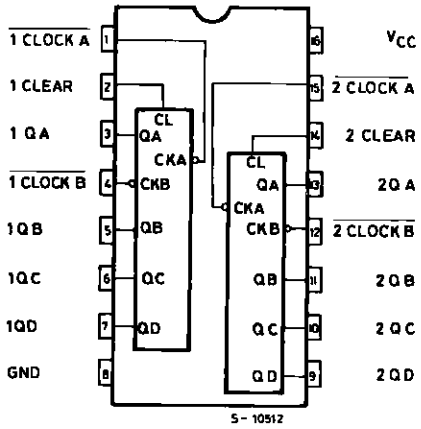
M1R
(Micro Package)

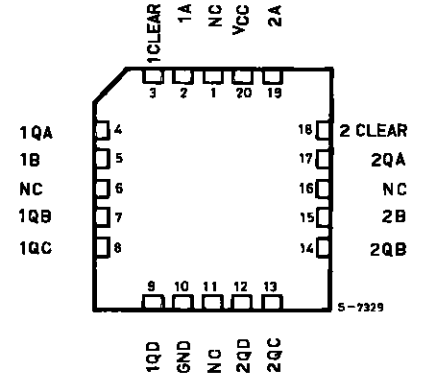
C1R
(Chip Carrier)

ORDER CODES :

M54HC390F1R M74HC390M1R
M74HC390B1R M74HC390C1R

PIN CONNECTIONS (top view)





NC = No Internal Con-

DESCRIPTION

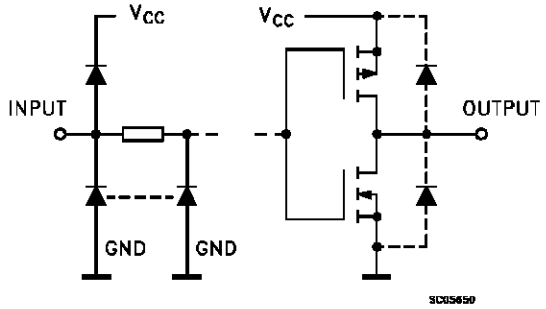
The M54/74HC390 is a high speed CMOS DUAL DECADE COUNTER fabricated in silicon gate C^2MOS technology. It has the same high speed performance of LSTTL combined with true CMOS low power consumption.

This dual decade counter contains two independent ripple carry counters. Each counter is composed of a divide-by-two and divide-by-five counter. The divide-by-two and divide-by-five counters can be cascaded to form dual decade, dual biquinary, or various combinations up to a single divide-by-100 counter.

Each 4-bit counter is incremented on the high to low transition (negative edge) of the clock input, and each has an independent clear input. When clear is set low all four bits of each counter are set to low. This enables count truncation and allows the implementation of divide-by-N counter configurations.

All inputs are equipped with protection circuits against static discharge and transient excess voltage.

INPUT AND OUTPUT EQUIVALENT CIRCUIT



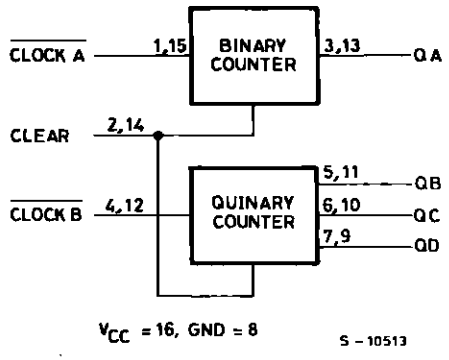
TRUTH TABLE

COUNT	OUTPUTS							
	BCD COUNT *				BI-QUINARY **			
	QD	QC	QB	QA	QA	QD	QC	QB
0	L	L	L	L	L	L	L	L
1	L	L	L	H	L	L	L	H
2	L	L	H	L	L	L	H	L
3	L	L	H	H	L	L	H	H
4	L	H	L	L	L	H	L	L
5	L	H	L	H	H	L	L	L
6	L	H	H	L	H	L	L	H
7	L	H	H	H	H	L	H	L
8	H	L	L	L	H	L	H	H
9	H	L	L	H	H	H	L	L

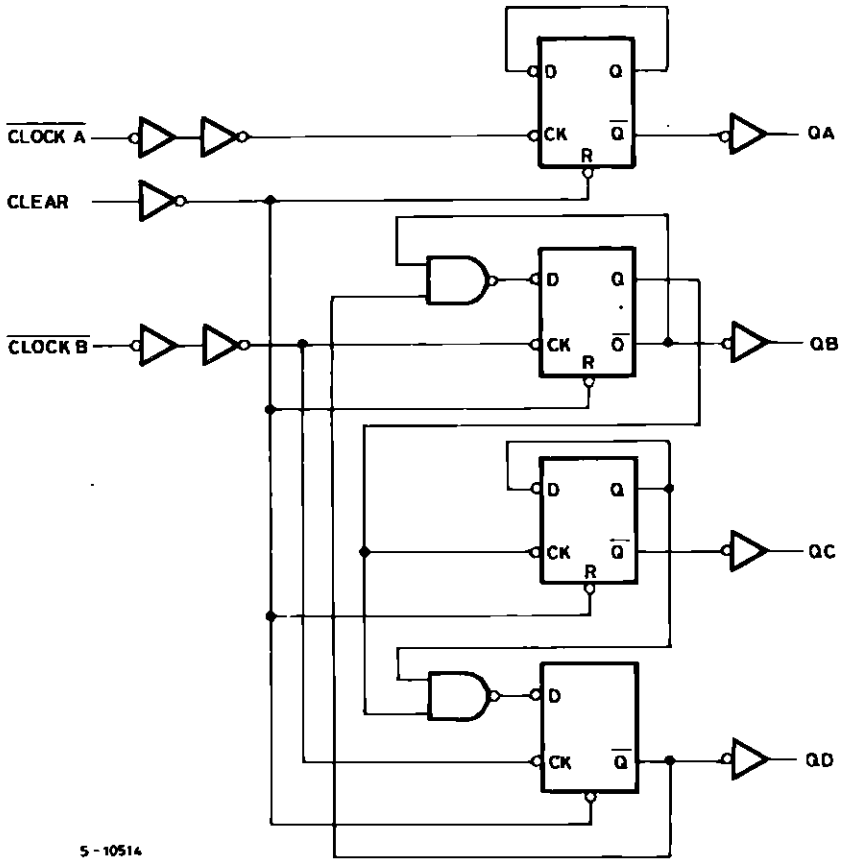
INPUTS			OUTPUTS			
$\overline{\text{CLOCK A}}$	$\overline{\text{CLOCK B}}$	CLEAR	QA	QB	QC	QD
X	X	H	L	L	L	L
⌐	X	L	BINARY COUNT UP			
X	⌐	L	QUINARY COUNT UP			

Note: * Output QA is connected to input $\overline{\text{CLOCK B}}$ for BCD count.
** Output QD is connected to input $\overline{\text{CLOCK A}}$ for bi-quinary count.

BLOCK DIAGRAM

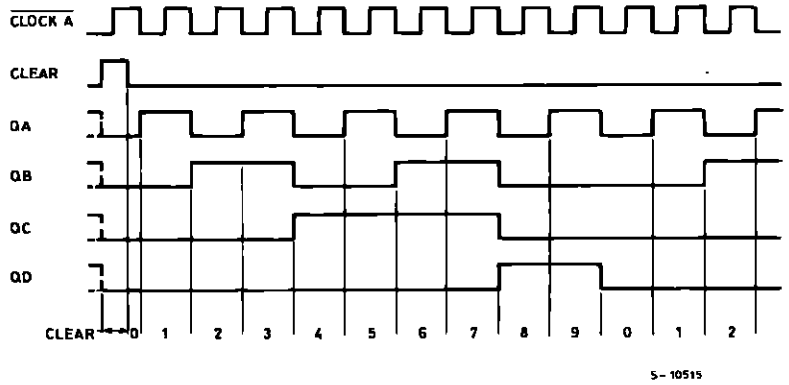


LOGIC DIAGRAM

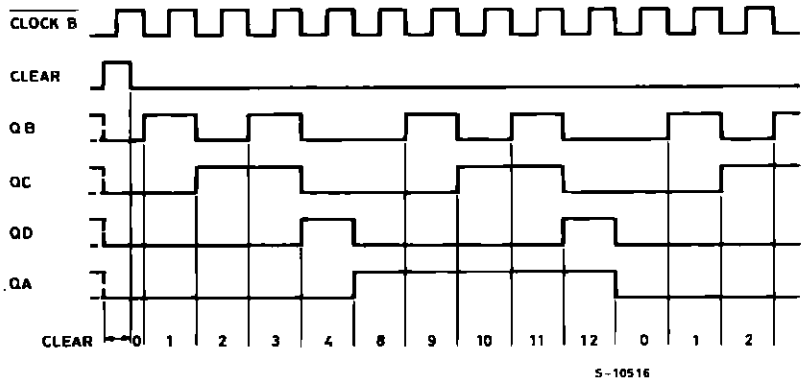


TIMING CHART

(1) BCD COUNT SEQUENCE *



(2) BI-QUINARY COUNT SEQUENCE **

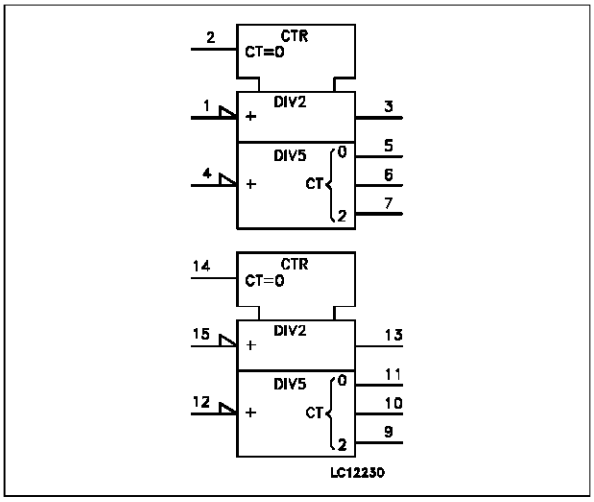


*OUTPUT QA IS CONNECTED TO INPUT $\overline{\text{CLOCK B}}$

PIN DESCRIPTION

PIN No	SYMBOL	NAME AND FUNCTION
1, 15	$\overline{1\ CLOCK\ A}$ 2 CLOCK B	Clock Input Divide by 2 Section (HIGH to LOW Edge-triggered)
2, 14	1 CLEAR 2 CLEAR	Asynchronous Master Reset Inputs
3, 5, 6, 7	1QA to 1QD	Flip Flop Outputs
4, 12	$\overline{1\ CLOCK\ B}$ 2 CLOCK B	Clock Input Divide by 5 Section (HIGH to LOW Edge-triggered)
13, 11, 10, 9	2QA to 2QD	Flip Flop Outputs
8	GND	Ground (0V)
16	V_{CC}	Positive Supply Voltage

IEC LOGIC SYMBOL



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	-0.5 to +7	V
V_I	DC Input Voltage	-0.5 to V_{CC} + 0.5	V
V_O	DC Output Voltage	-0.5 to V_{CC} + 0.5	V
I_{IK}	DC Input Diode Current	± 20	mA
I_{OK}	DC Output Diode Current	± 20	mA
I_O	DC Output Source Sink Current Per Output Pin	± 25	mA
I_{CC} or I_{GND}	DC V_{CC} or Ground Current	± 50	mA
P_D	Power Dissipation	500 (*)	mW
T_{stg}	Storage Temperature	-65 to +150	°C
T_L	Lead Temperature (10 sec)	300	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.
(*) 500 mW: ≅ 65 °C derate to 300 mW by 10mW/°C: 65 °C to 85 °C

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Value	Unit
V_{CC}	Supply Voltage		2 to 6	V
V_I	Input Voltage		0 to V_{CC}	V
V_O	Output Voltage		0 to V_{CC}	V
T_{op}	Operating Temperature: **M54HC** Series **M74HC** Series		-55 to +125 -40 to +85	°C °C
t_r, t_f	Input Rise and Fall Time	V_{CC} = 2 V	0 to 1000	ns
		V_{CC} = 4.5 V	0 to 500	
		V_{CC} = 6 V	0 to 400	

DC SPECIFICATIONS

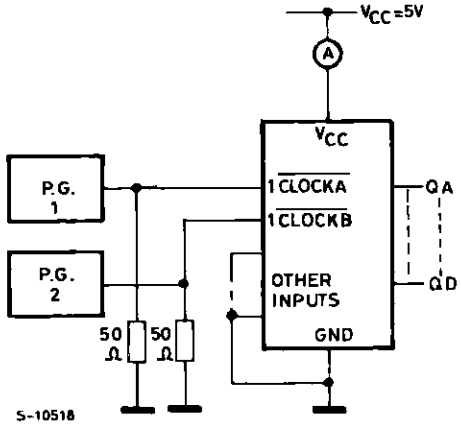
Symbol	Parameter	Test Conditions			Value							Unit
		V_{CC} (V)			T_A = 25 °C 54HC and 74HC			-40 to 85 °C 74HC		-55 to 125 °C 54HC		
					Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
V_{IH}	High Level Input Voltage	2.0			1.5			1.5		1.5		V
		4.5			3.15			3.15		3.15		
		6.0			4.2			4.2		4.2		
V_{IL}	Low Level Input Voltage	2.0					0.5		0.5		0.5	V
		4.5					1.35		1.35		1.35	
		6.0					1.8		1.8		1.8	
V_{OH}	High Level Output Voltage	2.0	V_I = V_{IH} or V_{IL}	I_O=-20 µA	1.9	2.0		1.9		1.9		V
		4.5			4.4	4.5		4.4		4.4		
		6.0			5.9	6.0		5.9		5.9		
		4.5		I_O=-4.0 mA	4.18	4.31		4.13		4.10		
		6.0		I_O=-5.2 mA	5.68	5.8		5.63		5.60		
V_{OL}	Low Level Output Voltage	2.0	V_I = V_{IH} or V_{IL}	I_O= 20 µA		0.0	0.1		0.1		0.1	V
		4.5				0.0	0.1		0.1		0.1	
		6.0				0.0	0.1		0.1		0.1	
		4.5		I_O= 4.0 mA		0.17	0.26		0.33		0.40	
		6.0		I_O= 5.2 mA		0.18	0.26		0.33		0.40	
I_I	Input Leakage Current	6.0	V_I = V_{CC} or GND				±0.1		±1		±1	µA
I_{CC}	Quiescent Supply Current	6.0	V_I = V_{CC} or GND				4		40		80	µA

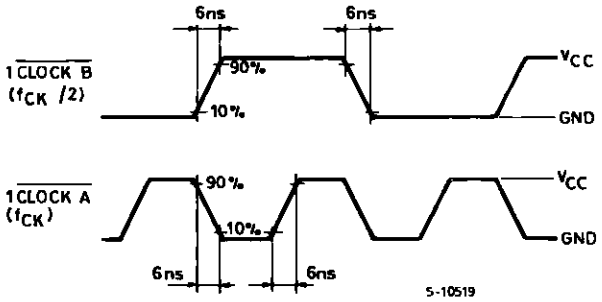
AC ELECTRICAL CHARACTERISTICS (C_L = 50 pF, Input $t_r = t_f$ = 6 ns)

Symbol	Parameter	Test Conditions		Value							Unit
		V_{CC} (V)		T_A = 25 °C 54HC and 74HC			-40 to 85 °C 74HC		-55 to 125 °C 54HC		
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
t_{TLH} t_{THL}	Output Transition Time	2.0			30	75		95		110	ns
		4.5			8	15		19		22	
		6.0			7	13		16		19	
t_{PLH} t_{PHL}	Propagation Delay Time (CLOCK A - QA)	2.0			42	120		150		180	ns
		4.5			14	24		30		36	
		6.0			12	20		26		31	
t_{PLH} t_{PHL}	Propagation Delay Time (CLOCK A - QB, QD)	2.0			45	120		150		180	ns
		4.5			15	24		30		36	
		6.0			13	20		26		31	
t_{PLH} t_{PHL}	Propagation Delay Time (CLOCK A - QC)	2.0	QA Connected to CKB		108	280		350		420	ns
		4.5			36	56		70		84	
		6.0			31	48		60		71	
t_{PLH} t_{PHL}	Propagation Delay Time (CLOCK B - QC)	2.0			72	185		230		280	ns
		4.5			24	37		46		56	
		6.0			20	31		39		48	
t_{PHL}	Propagation Delay Time (CLEAR - Qn	2.0			45	125		155		190	ns
		4.5			15	25		31		38	
		6.0			13	21		26		32	
f_{MAX}	Maximum Clock Frequency (CLOCK A - QA)	2.0		8.4	17		6.8		5.6		ns
		4.5		42	65		34		28		
		6.0		50	79		40		33		
f_{MAX}	Maximum Clock Frequency (CLOCK B - QB)	2.0		8.4	17		6.8		5.6		ns
		4.5		42	67		34		28		
		6.0		50	79		40		33		
$t_{W(H)}$ $t_{W(L)}$	Minimum Pulse Wisth (CLOCK)	2.0			24	75		95		110	ns
		4.5			6	15		19		22	
		6.0			5	13		16		19	
$t_{(W)H}$	Minimum Pulse Wisth (CLEAR)	2.0			24	75		95		110	ns
		4.5			6	15		19		22	
		6.0			5	13		16		19	
t_{REM}	Propagation Delay Time	2.0				25		30		35	ns
		4.5				5		6		7	
		6.0				5		5		6	
C_{IN}	Input Capacitance				5	10		10		10	pF
C_{PD} (*)	Power Dissipation Capacitance				84						pF

(*) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operting current can be obtained by the following equation. $I_{CC}(opr) = C_{PD} \bullet V_{CC} \bullet f_{IN} + I_{CC}$

TEST CIRCUIT I_{CC} (Opr.)



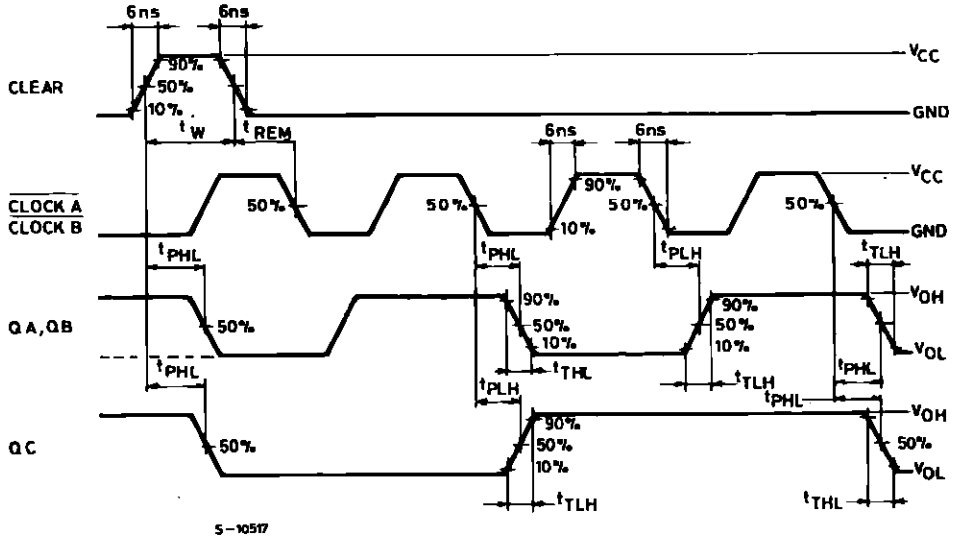


WHEN THE OUTPUTS DRIVE CAPACITIVE LOAD, TOTAL CURRENT CONSUMPTION IS TO BE A SUM OF THE VALUE CALCULATED FROM C_{PD} AND ΔI_{CC} OBTAINED FROM THE FOLLOWING FORMULA.

$$\Delta I_{CC} = f_{CK} \cdot V_{CC} \cdot \frac{Ca}{2} + \frac{f_{CK}}{2} \cdot V_{CC} \cdot \left(\frac{2Cb}{5} + \frac{Cc}{5} + \frac{Cd}{5} \right)$$

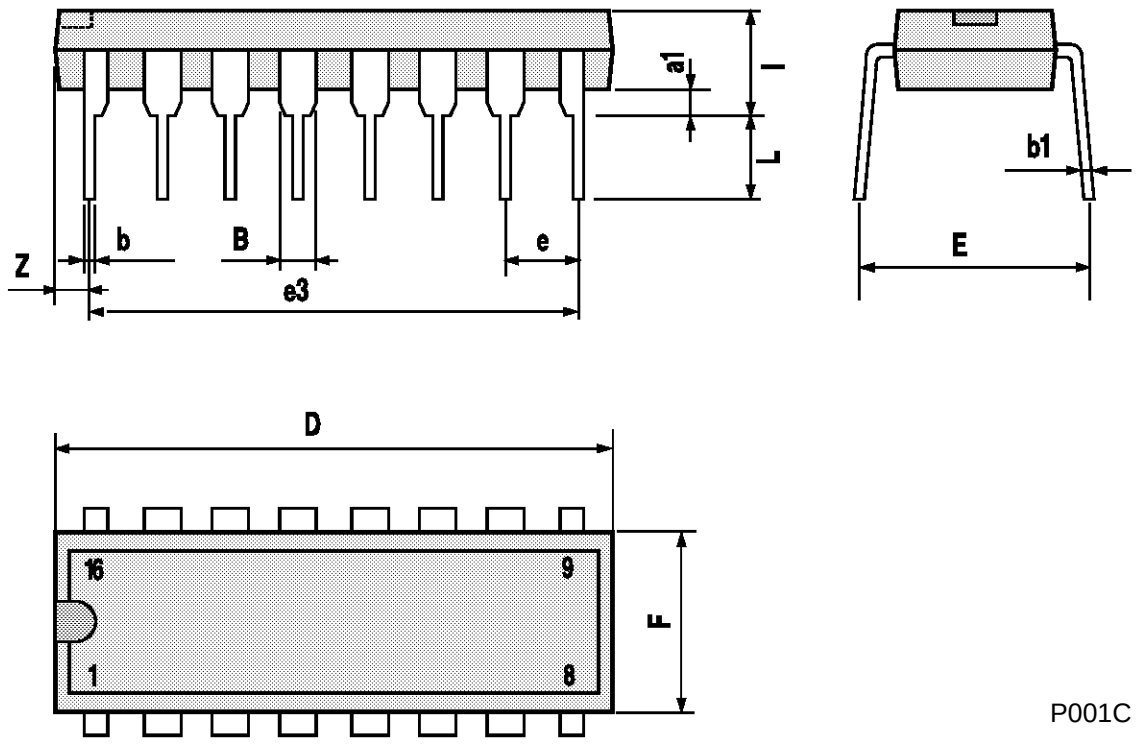
Ca – Cd ARE THE CAPACITANCE AT QA ~ QD OUTPUT.

SWITCHING CHARACTERISTICS TEST WAVEFORM



Plastic DIP16 (0.25) MECHANICAL DATA

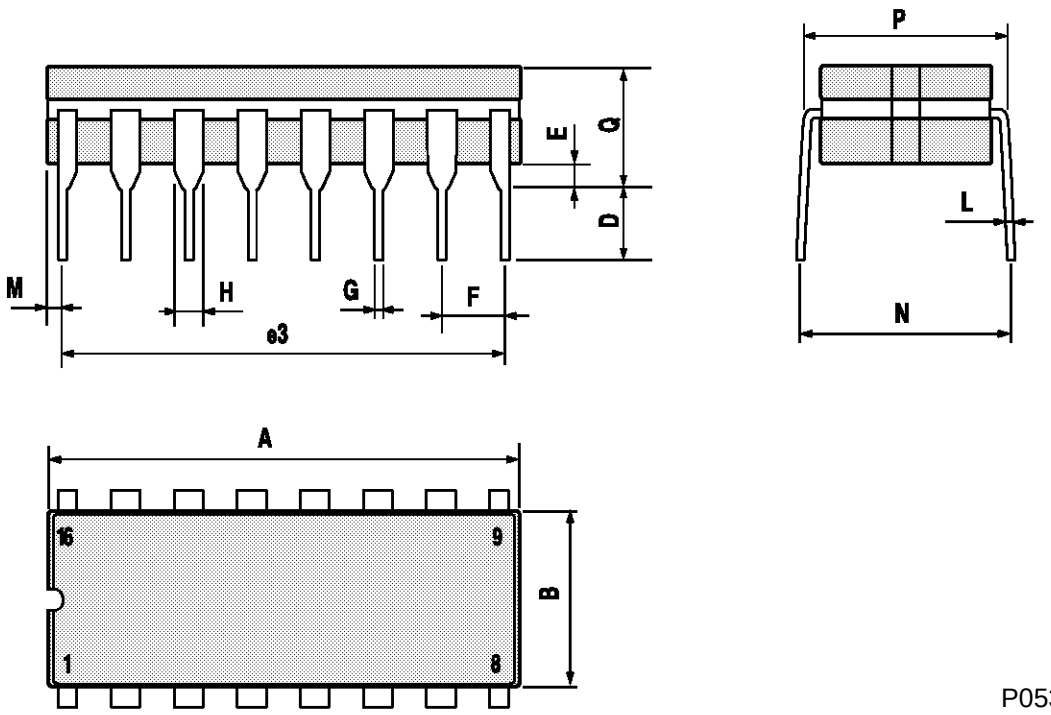
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	0.77		1.65	0.030		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		17.78			0.700	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z			1.27			0.050



P001C

Ceramic DIP16/1 MECHANICAL DATA

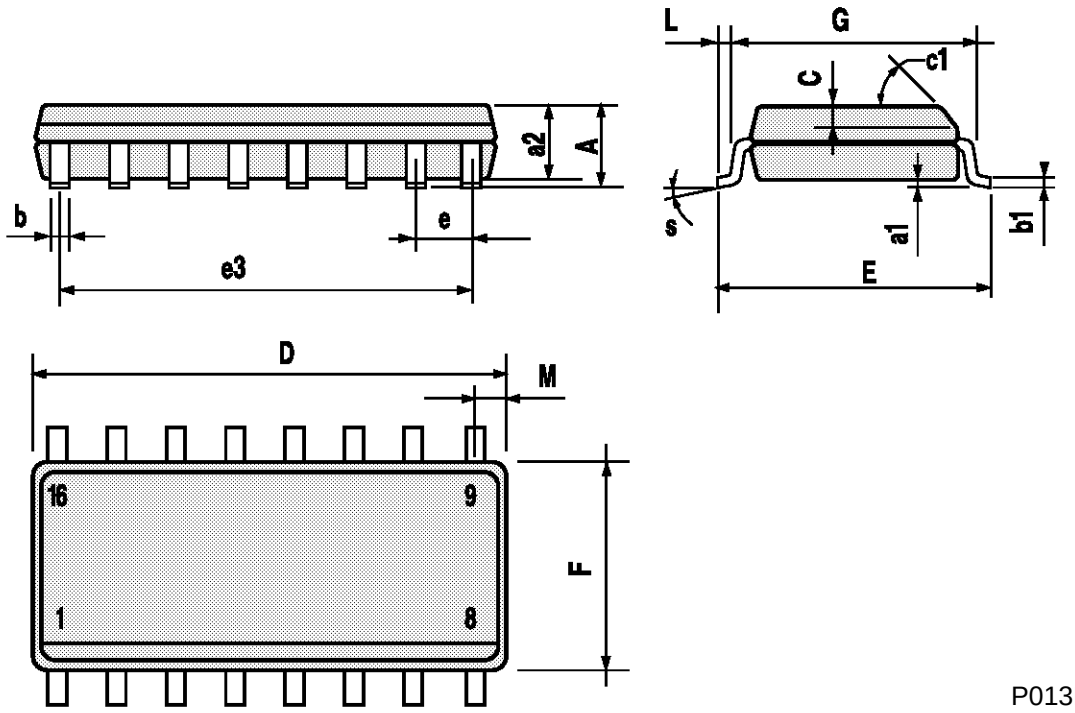
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			20			0.787
B			7			0.276
D		3.3			0.130	
E	0.38			0.015		
e3		17.78			0.700	
F	2.29		2.79	0.090		0.110
G	0.4		0.55	0.016		0.022
H	1.17		1.52	0.046		0.060
L	0.22		0.31	0.009		0.012
M	0.51		1.27	0.020		0.050
N			10.3			0.406
P	7.8		8.05	0.307		0.317
Q			5.08			0.200



P053D

SO16 (Narrow) MECHANICAL DATA

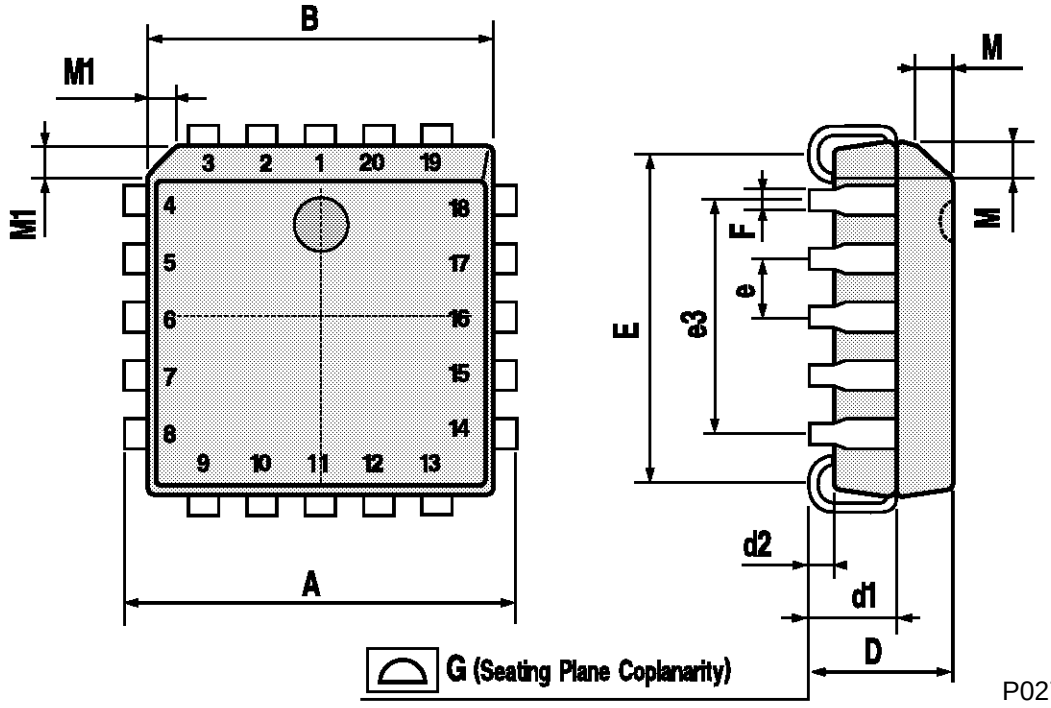
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			1.75			0.068
a1	0.1		0.2	0.004		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1	45° (typ.)					
D	9.8		10	0.385		0.393
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		8.89			0.350	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.62			0.024
S	8° (max.)					



P013H

PLCC20 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	9.78		10.03	0.385		0.395
B	8.89		9.04	0.350		0.356
D	4.2		4.57	0.165		0.180
d1		2.54			0.100	
d2		0.56			0.022	
E	7.37		8.38	0.290		0.330
e		1.27			0.050	
e3		5.08			0.200	
F		0.38			0.015	
G			0.101			0.004
M		1.27			0.050	
M1		1.14			0.045	



P027A